- Two Precision Timing Circuits per Package
- **Astable or Monostable Operation**
- **TTL-Compatible Output Can Sink or Source** Up to 150 mA
- **Active Pullup or Pulldown**
- Designed to be Interchangeable With Signetics NE556, SA556, and SE556
- **Applications Include:**
 - Precision Timers From Microseconds to
 - Pulse-Shaping Circuits
 - Missing-Pulse Detectors
 - Tone-Burst Generators
 - Pulse-Width Modulators
 - Pulse-Position Modulators
 - Sequential Timers
 - Pulse Generators
 - Frequency Dividers
 - Application Timers
 - Industrial Controls
 - Touch-Tone Encoders

NE556, SA556 . . . D, OR N PACKAGE SE556...J PACKAGE (TOP VIEW) 1DISCH[14 🛮 V_{CC} 1THRES∏ 13 ☐ 2DISCH 12 THRES 3 1RESET∏ 4 2CONT 10UT **1** 5 10 2RESET 1 20UT 6 9 GND [1 2TRIG 8

description

These devices provide two independent timing circuits of the NE555, SA555, or SE555 type in each package. These circuits can be operated in the astable or the monostable mode with external resistor-capacitor (RC) timing control. The basic timing provided by the RC time constant can be controlled actively by modulating the bias of the control-voltage input.

The threshold (THRES) and trigger (TRIG) levels are normally two-thirds and one-third, respectively, of V_{CC} . These levels can be altered by using the control-voltage (CONT) terminal. When the trigger input falls below trigger level, the flip-flop is set and the output goes high. If the trigger input is above the trigger level and the threshold input is above the threshold level, the flip-flop is reset and the output is low. The reset (RESET) input can override all other inputs and can be used to initiate a new timing cycle. When the reset input goes low, the flip-flop is reset and the output goes low. When the output is low, a low-impedance path is provided between the discharge (DISCH) terminal and ground (GND).

The NE556 is characterized for operation from 0°C to 70°C. The SA556 is characterized for operation from -40°C to 85°C, and the SE556 is characterized for operation over the full military range of -55°C to 125°C.

AVAILABLE OPTIONS

	\/_ (MAN)	PA	CKAGED DEVICES	
TA	V _T (MAX) V _{CC} = 15 V	SMALL OUTLINE (D)	CERAMIC DIP (J)	PLASTIC DIP (N)
0°C to 70°C	11.2 V	NE556D	-	NE556N
–40°C to 85°C	11.2 V	SA556D	-	SA556N
–55°C to 125°C	10.6 V	-	SE556J	_

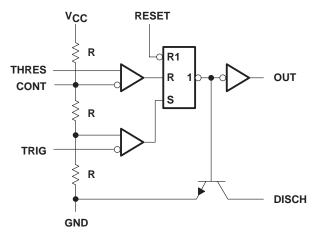
The D package is available taped and reeled. Add the suffix R to the device type (e.g., NE556DR).

FUNCTION TABLE (each timer)

RESET	TRIGGER VOLTAGET	THRESHOLD VOLTAGET	HRESHOLD VOLTAGE [†] OUTPUT		
Low	Irrelevant	Irrelevant	Low	On	
High	< 1/3 V _{DD}	Irrelevant	High	Off	
High	> 1/3 V _{DD}	> 2/3 V _{DD}	Low	On	
High	> 1/3 V _{DD}	> 2/3 V _{DD}	As previously established		

[†] Voltage levels shown are nominal.

functional block diagram, each timer



RESET can override TRIG, which can override THRES.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage, V _{CC} (see Note 1)	
Input voltage (CONT, RESET, THRES, and TRIG)	
Output current	
Continuous total dissipation	See Dissipation Rating Table
Package thermal impedance, θ_{JA} (see Note 2): D package	
N package	80°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J package	300°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D or N package	ge 260°C
Storage temperature range, T _{stq}	–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to network ground terminal.

2. The package thermal impedance is calculated in accordance with JESD 51.

DISSIPATION RATING TABLE

PACKAGE	TA $\leq 25^{\circ}$ C DERATING FACTOR ABOVE T _A = 25°C		T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	T _A = 125°C POWER RATING	
J	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW	



recommended operating conditions

		MIN	MAX	UNIT
Supply voltage Va -	NE556, SA556	4.5	16	V
Supply voltage, V _{CC}	SE556	4.5	18	V
Input voltage (CONT, RESET, THRES, and TRIG), V _I				V
Output current, IO				mA
	NE556	0	70	
Operating free-air temperature, T _A	SA556	-40	85	°C
	SE556	– 55	125	

electrical characteristics, V_{CC} = 5 V to 15 V, T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		NE5	NE556, SA556			SE556		
				MIN	TYP	MAX	MIN	TYP	MAX	UNIT
\/_	Throohold voltogo lovel	V _{CC} = 15 V		8.8	10	11.2	9.4	10	10.6	V
VT	Threshold voltage level	V _{CC} = 5 V		2.4	3.3	4.2	2.7	3.3	4	V
ΙΤ	Threshold current (see Note 3)				30	250		30	250	nA
\/	Triagor voltogo lovol	V _{CC} = 15 V		4.5	5	5.6	4.8	5	5.2	V
VTRIG	Trigger voltage level	V _{CC} = 5 V		1.1	1.67	2.2	1.45	1.67	1.9	V
ITRIG	Trigger current	TRIG at 0 V			0.5	2		0.5	0.9	μΑ
VRESET	Reset voltage level			0.3	0.7	1	0.3	0.7	1	V
l====	Reset current	RESET at V _C	C		0.1	0.4		0.1	0.4	A
IRESET	Reset current	RESET at 0 V	1		-0.4	1.5		-0.4	-1	mA
IDISCH	Discharge switch off-state current				20	100		20	100	nA
\/		V _{CC} = 15 V		9	10	11	9.6	10	10.4	V
VCONT	Control voltage (open circuit)	V _{CC} = 5 V	1		3.3	4	2.9	3.3	3.8	
	Low-level output voltage	V _{CC} = 15 V	$I_{OL} = 10 \text{ mA}$		0.1	0.25		0.1	0.15	V
			$I_{OL} = 50 \text{ mA}$		0.4	0.75		0.4	0.5	
VoL			I _{OL} = 100 mA		2	2.5		2	2.2	
VOL	Low-level output voltage		I _{OL} = 200 mA		2.5			2.5		
		V _{CC} = 5 V	$I_{OL} = 5 \text{ mA}$		0.1	0.25		0.1	0.15	
			$I_{OL} = 8 \text{ mA}$		0.15	0.3		0.15	0.25	
		V _{CC} = 15 V	$I_{OH} = -100 \text{ mA}$	12.75	13.3		13	13.3		V
V_{OH}	High-level output voltage	VCC = 13 V	$I_{OH} = -200 \text{ mA}$		12.5			12.5		
		$V_{CC} = 5 V$	$I_{OH} = -100 \text{ mA}$	2.75	3.3		3	3.3		
	Supply current	Output low, No Load	V _{CC} = 15 V		20	30		20	24	mA
Icc			V _{CC} = 5 V		6	12		6	10	
.00		Output high, No load	V _{CC} = 15 V		18	26		18	20	nA
			$V_{CC} = 5 V$		4	10		4	8	ПА

NOTE 3: This parameter influences the maximum value of the timing resistors R_A and R_B in the circuit of Figure 1. For example, when V_{CC} = 5 V, the maximum value is $R = R_A + R_B \approx 3.4$ M Ω , and for V_{CC} = 15 V, the maximum value is R_A = 10 M Ω .

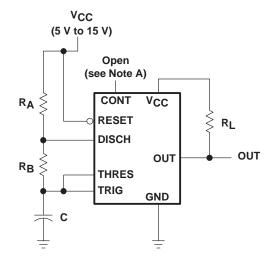


operating characteristics, $V_{CC} = 5 V$ and 15 V

PARAMETER		TEST	NE556, SA556			SE556			UNIT
		CONDITIONS†	MIN	TYP	MAX	MIN	TYP	MAX	UNII
	Each timer, monostable§			1	3		0.5	1.5	
Initial error of timing interval‡	Each timer, astable¶	T _A = 25°C		2.25%			1.5%		
	Timer 1 — Timer 2			±1			±0.5		
	Each timer, monostable§	T _A = MIN to MAX		50			30	100	ppm/°C
Temperature coefficient of timing interval	Each timer, astable¶			150			90		
tirring interval	Timer 1 — Timer 2			±10			±10		
	Each timer, monostable§	T _A = 25°C		0.1	0.5		0.05	0.2	
Supply voltage sensitivity of timing interval	Each timer, astable¶			0.3			0.15		%/V
tirriirig iritervai	Timer 1 — Timer 2			±0.2			±0.1]
Output pulse rise time		$C_L = 15 pF,$		100	300		100	200	no
Output pulse fall time		T _A = 25°C		100	300		100	200	ns

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

APPLICATION INFORMATION



NOTE A: Bypassing the control-voltage input to ground with a capacitor may improve operation. This should be evaluated for individual applications.

VCC (5 V to 15 V) $0.01 \mu F >$ CONT **VCC** R_A **RESET** R_L **DISCH** OUT OUT **THRES TRIG INPUT** GND С

Figure 2. Circuit for Monostable Operation

Figure 1. Circuit for Astable Operation

[‡] Timing interval error is defined as the difference between the measured value and the average value of a random sample from each process run.

 $[\]S$ Values specified are for a device in a monostable circuit similar to Figure 2, with component values as follow: $R_A = 2 \text{ k}\Omega$ to 100 k Ω , $C = 0.1 \mu F$.

[¶] Values specified are for a device in an astable circuit similar to Figure 1, with component values as follow: RA = 1 kΩ to 100 kΩ, C = 0.1μF.

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